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#### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

## Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

### Details

Product StatusNot For New DesignsCore ProcessorC166SV2Core Size16/32-BitSpeed80MHzConnectivityCANbus, EBI/EMI, I²C, LINbus, SPI, SSC, UART/USART, USIPeripheralsI²S, POR, PWM, WDTNumber of I/O116Program Memory Size832KB (832K x 8)Program Memory TypeFLASHEEPROM Size-RAM Size50K x 8Voltage - Supply (Vcc/Vdd)3V ~ 5.5VData ConvertersA/D 24x10b	
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EEPROM Size     -       RAM Size     50K x 8       Voltage - Supply (Vcc/Vdd)     3V ~ 5.5V	
RAM Size         50K x 8           Voltage - Supply (Vcc/Vdd)         3V ~ 5.5V	
Voltage - Supply (Vcc/Vdd) 3V ~ 5.5V	
Data Converters A/D 24x10b	
Oscillator Type Internal	
Operating Temperature -40°C ~ 125°C (TA)	
Mounting Type Surface Mount	
Package / Case     144-LQFP Exposed Pad	
Supplier Device Package PG-LQFP-144-4	
Purchase URL https://www.e-xfl.com/product-detail/infineon-technologies/xc2785x104f80lral	

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



#### Summary of Features

- Two Synchronizable A/D Converters with a total of up to 24 channels, 10-bit resolution, conversion time below 1  $\mu$ s, optional data preprocessing (data reduction, range check), broken wire detection
- Up to 6 serial interface channels to be used as UART, LIN, high-speed synchronous channel (SPI), IIC bus interface (10-bit addressing, 400 kbit/s), IIS interface
- On-chip MultiCAN interface (Rev. 2.0B active) with up to 64 message objects (Full CAN/Basic CAN) on up to 2 CAN nodes and gateway functionality
- On-chip system timer and on-chip real time clock
- Up to 12 Mbytes external address space for code and data
  - Programmable external bus characteristics for different address ranges
  - Multiplexed or demultiplexed external address/data buses
  - Selectable address bus width
  - 16-bit or 8-bit data bus width
  - Five programmable chip-select signals
  - Hold- and hold-acknowledge bus arbitration support
- Single power supply from 3.0 V to 5.5 V
- Programmable watchdog timer and oscillator watchdog
- Up to 119 general purpose I/O lines
- On-chip bootstrap loaders
- Supported by a full range of development tools including C compilers, macroassembler packages, emulators, evaluation boards, HLL debuggers, simulators, logic analyzer disassemblers, programming boards
- On-chip debug support via Device Access Port (DAP) or JTAG interface
- 144-pin Green LQFP package, 0.5 mm (19.7 mil) pitch



# 2.1 Pin Configuration and Definition

The pins of the XC2785X are described in detail in **Table 6**, which includes all alternate functions. For further explanations please refer to the footnotes at the end of the table. The following figure summarizes all pins, showing their locations on the four sides of the package.

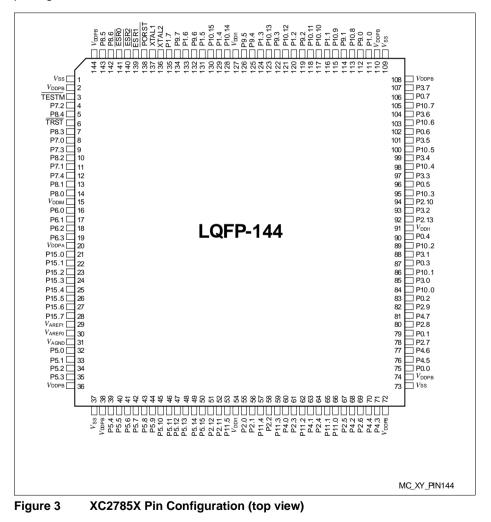




Table 6         Pin Definitions and Functions (cont'd)					
Pin	Symbol	Ctrl.	Туре	Function	
82	P2.9	O0 / I	St/B	Bit 9 of Port 2, General Purpose Input/Output	
	U0C1_DOUT	01	St/B	USIC0 Channel 1 Shift Data Output	
	TxDC1	O2	St/B	CAN Node 1 Transmit Data Output	
	CC2_CC22	O3 / I	St/B	CAPCOM2 CC22IO Capture Inp./ Compare Out.	
	A22	ОН	St/B	External Bus Interface Address Line 22	
	CLKIN1	I	St/B	Clock Signal Input 1	
	TCK_A	IH	St/B	<b>DAP0/JTAG Clock Input</b> If JTAG pos. A is selected during start-up, an internal pull-up device will hold this pin high when nothing is driving it. If DAP pos. 0 is selected during start-up, an internal pull-down device will hold this pin low when nothing is driving it.	
83	P0.2	O0 / I	St/B	Bit 2 of Port 0, General Purpose Input/Output	
	U1C0_SCLK OUT	O1	St/B	USIC1 Channel 0 Shift Clock Output	
	TxDC0	O2	St/B	CAN Node 0 Transmit Data Output	
	CCU61_CC6 2	O3	St/B	CCU61 Channel 2 Output	
	A2	ОН	St/B	External Bus Interface Address Line 2	
	U1C0_DX1B	I	St/B	USIC1 Channel 0 Shift Clock Input	
	CCU61_CC6 2INA	I	St/B	CCU61 Channel 2 Input	



Table 6         Pin Definitions and Functions (cont'd)						
Pin	Symbol	Ctrl.	Туре	Function		
99	P3.4	O0 / I	St/B	Bit 4 of Port 3, General Purpose Input/Output		
	U2C1_SELO 0	O1	St/B	USIC2 Channel 1 Select/Control 0 Output		
	U2C0_SELO 1	02	St/B	USIC2 Channel 0 Select/Control 1 Output		
	U0C0_SELO 4	O3	St/B	USIC0 Channel 0 Select/Control 4 Output		
	U2C1_DX2A	I	St/B	USIC2 Channel 1 Shift Control Input		
100	P10.5	O0 / I	St/B	Bit 5 of Port 10, General Purpose Input/Output		
	U0C1_SCLK OUT	O1	St/B	USIC0 Channel 1 Shift Clock Output		
	CCU60_COU T62	02	St/B	CCU60 Channel 2 Output		
	U2C0_DOUT	O3	St/B	USIC2 Channel 0 Shift Data Output		
	AD5	OH / IH	St/B	External Bus Interface Address/Data Line 5		
	U0C1_DX1B	I	St/B	USIC0 Channel 1 Shift Clock Input		
101	P3.5	O0 / I	St/B	Bit 5 of Port 3, General Purpose Input/Output		
	U2C1_SCLK OUT	01	St/B	USIC2 Channel 1 Shift Clock Output		
	U2C0_SELO 2	O2	St/B	USIC2 Channel 0 Select/Control 2 Output		
	U0C0_SELO 5	O3	St/B	USIC0 Channel 0 Select/Control 5 Output		
	U2C1_DX1A	I	St/B	USIC2 Channel 1 Shift Clock Input		



Table 6         Pin Definitions and Functions (cont'd)						
Pin	Symbol	Ctrl.	Туре	Function		
105	P10.7	O0 / I	St/B	Bit 7 of Port 10, General Purpose Input/Output		
	U0C1_DOUT	O1	St/B	USIC0 Channel 1 Shift Data Output		
	CCU60_COU T63	O2	St/B	CCU60 Channel 3 Output		
	AD7	OH / IH	St/B	External Bus Interface Address/Data Line 7		
	U0C1_DX0B	I	St/B	USIC0 Channel 1 Shift Data Input		
	CCU60_CCP OS0A	1	St/B	CCU60 Position Input 0		
	T4INB	I	St/B	GPT12E Timer T4 Count/Gate Input		
106	P0.7	O0 / I	St/B	Bit 7 of Port 0, General Purpose Input/Output		
	U1C1_DOUT	01	St/B	USIC1 Channel 1 Shift Data Output		
	U1C0_SELO 3	O2	St/B	USIC1 Channel 0 Select/Control 3 Output		
	A7	ОН	St/B	External Bus Interface Address Line 7		
	U1C1_DX0B	I	St/B	USIC1 Channel 1 Shift Data Input		
	CCU61_CTR APB	1	St/B	CCU61 Emergency Trap Input		
107	P3.7	O0 / I	St/B	Bit 7 of Port 3, General Purpose Input/Output		
	U2C1_DOUT	O1	St/B	USIC2 Channel 1 Shift Data Output		
	U2C0_SELO 3	O2	St/B	USIC2 Channel 0 Select/Control 3 Output		
	U0C0_SELO 7	O3	St/B	USIC0 Channel 0 Select/Control 7 Output		
	U2C1_DX0B	I	St/B	USIC2 Channel 1 Shift Data Input		



Table 6         Pin Definitions and Functions (cont'd)						
Pin	Symbol	Ctrl.	Туре	Function		
120	P1.2	O0 / I	St/B	Bit 2 of Port 1, General Purpose Input/Output		
	CCU62_CC6 2	01	St/B	CCU62 Channel 2 Output		
	U1C0_SELO 6	02	St/B	USIC1 Channel 0 Select/Control 6 Output		
	U2C1_SCLK OUT	O3	St/B	USIC2 Channel 1 Shift Clock Output		
	A10	ОН	St/B	External Bus Interface Address Line 10		
	ESR1_4	1	St/B	ESR1 Trigger Input 4		
	CCU61_T12 HRB	I	St/B	External Run Control Input for T12 of CCU61		
	CCU62_CC6 2INA	I	St/B	CCU62 Channel 2 Input		
	U2C1_DX0D	I	St/B	USIC2 Channel 1 Shift Data Input		
	U2C1_DX1C	I	St/B	USIC2 Channel 1 Shift Clock Input		
121	P10.12	O0 / I	St/B	Bit 12 of Port 10, General Purpose Input/Output		
	U1C0_DOUT	01	St/B	USIC1 Channel 0 Shift Data Output		
	TDO_B	OH / IH	St/B	JTAG Test Data Output / DAP1 Input/Output If DAP pos. 1 is selected during start-up, an internal pull-down device will hold this pin low when nothing is driving it.		
	AD12	OH / IH	St/B	External Bus Interface Address/Data Line 12		
	U1C0_DX0C	I	St/B	USIC1 Channel 0 Shift Data Input		
	U1C0_DX1E	I	St/B	USIC1 Channel 0 Shift Clock Input		
122	P9.3	O0 / I	St/B	Bit 3 of Port 9, General Purpose Input/Output		
	CCU63_COU T60	01	St/B	CCU63 Channel 0 Output		
	BRKOUT	O2	St/B	OCDS Break Signal Output		



Table 6         Pin Definitions and Functions (cont'd)									
Pin	Symbol	Ctrl.	Туре	Function					
134	P9.7	O0 / I	St/B	Bit 7 of Port 9, General Purpose Input/Output					
	CCU62_COU T60	O1	St/B	CCU62 Channel 0 Output					
	CCU62_COU T63	O2	St/B	CCU62 Channel 3 Output					
	CCU63_CTR APB	I	St/B	CCU63 Emergency Trap Input					
	U2C0_DX1D	I	St/B	USIC2 Channel 0 Shift Clock Input					
	CCU60_CCP OS0B	I	St/B	CCU60 Position Input 0					
135	P1.7	O0 / I	St/B	Bit 7 of Port 1, General Purpose Input/Output					
	CCU62_CC6 0	O1	St/B	CCU62 Channel 0 Output					
	U1C1_MCLK OUT	O2	St/B	USIC1 Channel 1 Master Clock Output					
	U2C0_SCLK OUT	O3	St/B	USIC2 Channel 0 Shift Clock Output					
	A15	ОН	St/B	External Bus Interface Address Line 15					
	U2C0_DX1C	I	St/B	USIC2 Channel 0 Shift Clock Input					
	CCU62_CC6 0INA	I	St/B	CCU62 Channel 0 Input					
136	XTAL2	0	Sp/M	Crystal Oscillator Amplifier Output					
137	XTAL1	I	Sp/M	<b>Crystal Oscillator Amplifier Input</b> To clock the device from an external source, drive XTAL1, while leaving XTAL2 unconnected. Voltages on XTAL1 must comply to the core supply voltage $V_{\text{DDIM}}$ .					
	ESR2_9	1	St/B	ESR2 Trigger Input 9					



### **Functional Description**

# 3.2 External Bus Controller

All external memory access operations are performed by a special on-chip External Bus Controller (EBC). The EBC also controls access to resources connected to the on-chip LXBus (MultiCAN and the USIC modules). The LXBus is an internal representation of the external bus that allows access to integrated peripherals and modules in the same way as to external components.

The EBC can be programmed either to Single Chip Mode, when no external memory is required, or to an external bus mode with the following selections<sup>1)</sup>:

- Address Bus Width with a range of 0 ... 24-bit
- Data Bus Width 8-bit or 16-bit
- Bus Operation Multiplexed or Demultiplexed

The bus interface uses Port 10 and Port 2 for addresses and data. In the demultiplexed bus modes, the lower addresses are output separately on Port 0 and Port 1. The number of active segment address lines is selectable, restricting the external address space to 8 Mbytes ... 64 Kbytes. This is required when interface lines shall be assigned to Port 2.

External  $\overline{CS}$  signals (address windows plus default) can be generated and output on Port 4 in order to save external glue logic. External modules can be directly connected to the common address/data bus and their individual select lines.

A HOLD/HLDA protocol is available for bus arbitration; this allows the sharing of external resources with other bus masters. The bus arbitration is enabled by software, after which pins P3.0 ... P3.2 (BREQ, HLDA, HOLD) are automatically controlled by the EBC. In Master Mode (default after reset) the HLDA pin is an output. In Slave Mode pin HLDA is switched to be an input. This allows the direct connection of the slave controller to another master controller without glue logic.

Important timing characteristics of the external bus interface are programmable (with registers TCONCSx/FCONCSx) to allow the user to adapt it to a wide range of different types of memories and external peripherals.

Access to very slow memories or modules with varying access times is supported by a special 'Ready' function. The active level of the control input signal is selectable.

In addition, up to four independent address windows may be defined (using registers ADDRSELx) to control access to resources with different bus characteristics. These address windows are arranged hierarchically where window 4 overrides window 3, and window 2 overrides window 1. All accesses to locations not covered by these four address windows are controlled by TCONCS0/FCONCS0. The currently active window can generate a chip select signal.

The external bus timing is based on the rising edge of the reference clock output CLKOUT. The external bus protocol is compatible with that of the standard C166 Family.

<sup>1)</sup> Bus modes are switched dynamically if several address windows with different mode settings are used.



### **Functional Description**

to a dedicated vector table location). The occurrence of a hardware trap is also indicated by a single bit in the trap flag register (TFR). Unless another higher-priority trap service is in progress, a hardware trap will interrupt any ongoing program execution. In turn, hardware trap services can normally not be interrupted by standard or PEC interrupts.

Depending on the package option up to 3 External Service Request (ESR) pins are provided. The ESR unit processes their input values and allows to implement user controlled trap functions (System Requests SR0 and SR1). In this way reset, wakeup and power control can be efficiently realized.

Software interrupts are supported by the 'TRAP' instruction in combination with an individual trap (interrupt) number. Alternatively to emulate an interrupt by software a program can trigger interrupt requests by writing the Interrupt Request (IR) bit of an interrupt control register.

# 3.7 On-Chip Debug Support (OCDS)

The On-Chip Debug Support system built into the XC2785X provides a broad range of debug and emulation features. User software running on the XC2785X can be debugged within the target system environment.

The OCDS is controlled by an external debugging device via the debug interface. This either consists of the 2-pin Device Access Port (DAP) or of the JTAG port conforming to IEEE-1149. The debug interface can be completed with an optional break interface.

The debugger controls the OCDS with a set of dedicated registers accessible via the debug interface (DAP or JTAG). In addition the OCDS system can be controlled by the CPU, e.g. by a monitor program. An injection interface allows the execution of OCDS-generated instructions by the CPU.

Multiple breakpoints can be triggered by on-chip hardware, by software, or by an external trigger input. Single stepping is supported, as is the injection of arbitrary instructions and read/write access to the complete internal address space. A breakpoint trigger can be answered with a CPU halt, a monitor call, a data transfer, or/and the activation of an external signal.

Tracing data can be obtained via the debug interface, or via the external bus interface for increased performance.

Tracing of program execution is supported by the XC2000 Family emulation device.

The DAP interface uses two interface signals, the JTAG interface uses four interface signals, to communicate with external circuitry. The debug interface can be amended with two optional break lines.



### **Functional Description**

# 3.19 Instruction Set Summary

Table 11 lists the instructions of the XC2785X.

The addressing modes that can be used with a specific instruction, the function of the instructions, parameters for conditional execution of instructions, and the opcodes for each instruction can be found in the "**Instruction Set Manual**".

This document also provides a detailed description of each instruction.

Mnemonic	Description	Bytes		
ADD(B)	Add word (byte) operands	2/4		
ADDC(B)	Add word (byte) operands with Carry	2/4		
SUB(B)	Subtract word (byte) operands	2/4		
SUBC(B)	Subtract word (byte) operands with Carry	2/4		
MUL(U)	(Un)Signed multiply direct GPR by direct GPR $(16- \times 16-bit)$			
DIV(U)	(Un)Signed divide register MDL by direct GPR (16-/16-bit)	2		
DIVL(U)	(Un)Signed long divide reg. MD by direct GPR (32-/16-bit)	2		
CPL(B)	Complement direct word (byte) GPR	2		
NEG(B)	Negate direct word (byte) GPR	2		
AND(B)	Bitwise AND, (word/byte operands)	2/4		
OR(B)	Bitwise OR, (word/byte operands)	2/4		
XOR(B)	Bitwise exclusive OR, (word/byte operands)	2/4		
BCLR/BSET	Clear/Set direct bit	2		
BMOV(N)	Move (negated) direct bit to direct bit	4		
BAND/BOR/BXOR	AND/OR/XOR direct bit with direct bit	4		
BCMP	Compare direct bit to direct bit	4		
BFLDH/BFLDL	Bitwise modify masked high/low byte of bit-addressable direct word memory with immediate data	4		
CMP(B)	Compare word (byte) operands	2/4		
CMPD1/2	Compare word data to GPR and decrement GPR by 1/2	2/4		
CMPI1/2	Compare word data to GPR and increment GPR by 1/2	2/4		
PRIOR	Determine number of shift cycles to normalize direct word GPR and store result in direct word GPR	2		
SHL/SHR	Shift left/right direct word GPR	2		

### Table 11 Instruction Set Summary



# 4.2.1 DC Parameters

Keeping signal levels within the limits specified in this table ensures operation without overload conditions. For signal levels outside these specifications, also refer to the specification of the overload current  $I_{\text{OV}}$ .

Note: Operating Conditions apply.

 Table 14 is valid under the following conditions:

 $V_{\text{DDP}} \ge 4.5 \text{ V}; V_{\text{DDPtvp}} = 5 \text{ V}; V_{\text{DDP}} \le 5.5 \text{ V}$ 

Parameter	Symbol		Values	5	Unit	Note /
		Min.	Тур.	Max.		Test Condition
Pin capacitance (digital inputs/outputs). To be doubled for double bond pins. <sup>1)</sup>	C <sub>IO</sub> CC	_	-	10	pF	not subject to production test
Input Hysteresis <sup>2)</sup>	HYS CC	0.11  x $V_{\text{DDP}}$	_	-	V	$R_{\rm S} = 0$ Ohm
Absolute input leakage current on pins of analog ports <sup>3)</sup>	I <sub>OZ1</sub>   CC	-	10	200	nA	$V_{\rm IN}$ > 0 V; $V_{\rm IN}$ < $V_{\rm DDP}$
Absolute input leakage current for all other pins. To be doubled for double	I <sub>OZ2</sub>   CC	-	0.2	5	μA	$T_{\rm J} \leq 110 ~^{\circ}{\rm C};$ $V_{\rm IN} < V_{\rm DDP};$ $V_{\rm IN} > V_{\rm SS}$
bond pins. <sup>3)1)4)</sup>		-	0.2	15	μA	$T_{ m J} \leq$ 150 °C; $V_{ m IN} < V_{ m DDP};$ $V_{ m IN} > V_{ m SS}$
Pull Level Force Current <sup>5)</sup>	$ I_{PLF} $ SR	250	-	-	μA	6)
Pull Level Keep Current <sup>7)</sup>	I <sub>PLK</sub>   SR	-	-	30	μA	6)
Input high voltage (all except XTAL1)	$V_{\rm IH}{\rm SR}$	0.7  x $V_{\text{DDP}}$	-	V <sub>DDP</sub> + 0.3	V	
Input low voltage (all except XTAL1)	$V_{\rm IL}{ m SR}$	-0.3	-	$0.3  ext{ x}$ $V_{ ext{DDP}}$	V	
Output High voltage <sup>8)</sup>	V <sub>OH</sub> CC	V <sub>DDP</sub> - 1.0	_	-	V	$I_{\rm OH} \ge I_{\rm OHmax}$
		V <sub>DDP</sub> - 0.4	_	-	V	$I_{\rm OH} \ge I_{\rm OHnom}^{9)}$

# Table 14 DC Characteristics for Upper Voltage Range



Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.		Test Condition
Output Low Voltage <sup>8)</sup>	$V_{\rm OL}{\rm CC}$	-	-	1.0	V	$I_{\rm OL} \leq I_{\rm OLmax}$
		-	-	0.4	V	$I_{\rm OL} \leq I_{\rm OLnom}^{10)}$

#### Table 15 DC Characteristics for Lower Voltage Range (cont'd)

1) Because each double bond pin is connected to two pads (standard pad and high-speed pad), it has twice the normal value. For a list of affected pins refer to the pin definitions table in chapter 2.

- 2) Not subject to production test verified by design/characterization. Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It cannot suppress switching due to external system noise under all conditions.
- 3) If the input voltage exceeds the respective supply voltage due to ground bouncing ( $V_{\rm IN} < V_{\rm SS}$ ) or supply ripple ( $V_{\rm IN} > V_{\rm DDP}$ ), a certain amount of current may flow through the protection diodes. This current adds to the leakage current. An additional error current ( $I_{\rm INJ}$ ) will flow if an overload current flows through an adjacent pin. Please refer to the definition of the overload coupling factor  $K_{\rm CV}$ .
- 4) The given values are worst-case values. In production test, this leakage current is only tested at 125 °C; other values are ensured by correlation. For derating, please refer to the following descriptions: Leakage derating depending on temperature (*T*<sub>J</sub> = junction temperature [°C]): *I*<sub>OZ</sub> = 0.05 x e<sup>(1.5 + 0.028 x TJ-)</sup> [µA]. For example, at a temperature of 95 °C the resulting leakage current is 3.2 µA. Leakage derating depending on voltage level (DV = *V*<sub>DDP</sub> *V*<sub>PIN</sub> [V]): *I*<sub>OZ</sub> = *I*<sub>OZtempmax</sub> (1.6 x DV) (µA]. This voltage derating formula is an approximation which applies for maximum temperature.
- Drive the indicated minimum current through this pin to change the default pin level driven by the enabled pull device: V<sub>PIN</sub> <= V<sub>IL</sub> for a pullup; V<sub>PIN</sub> >= V<sub>IH</sub> for a pulldown.
- 6) These values apply to the fixed pull-devices in dedicated pins and to the user-selectable pull-devices in general purpose IO pins.
- 7) Limit the current through this pin to the indicated value so that the enabled pull device can keep the default pin level: V<sub>PIN</sub> >= V<sub>IH</sub> for a pullup; V<sub>PIN</sub> <= V<sub>IL</sub> for a pulldown.
- 8) The maximum deliverable output current of a port driver depends on the selected output driver mode. This specification is not valid for outputs which are switched to open drain mode. In this case the respective output will float and the voltage is determined by the external circuit.
- 9) As a rule, with decreasing output current the output levels approach the respective supply level (VOL->VSS, VOH->VDDP). However, only the levels for nominal output currents are verified.
- 10) As a rule, with decreasing output current the output levels approach the respective supply level ( $V_{OL}$ -> $V_{SS}$ ,  $V_{OH}$ -> $V_{DDP}$ ). However, only the levels for nominal output currents are verified.



## PLL frequency band selection

Different frequency bands can be selected for the VCO so that the operation of the PLL can be adjusted to a wide range of input and output frequencies:

Parameter	Symbol		Values		Unit	Note /
		Min.	Тур.	Max.		Test Condition
VCO output frequency	$f_{\rm VCO}{\rm CC}$	50	-	110	MHz	$VCOSEL = 00_B$
(VCO controlled)		100	-	160	MHz	$VCOSEL = 01_B$
VCO output frequency	$f_{\rm VCO}$ CC	10	-	40	MHz	$VCOSEL = 00_B$
(VCO free-running)		20	-	80	MHz	$VCOSEL = 01_B$

## Table 24 System PLL Parameters

# 4.6.2.2 Wakeup Clock

When wakeup operation is selected (SYSCON0.CLKSEL =  $00_B$ ), the system clock is derived from the low-frequency wakeup clock source:

 $f_{SYS} = f_{WU}$ .

In this mode, a basic functionality can be maintained without requiring an external clock source and while minimizing the power consumption.

## 4.6.2.3 Selecting and Changing the Operating Frequency

When selecting a clock source and the clock generation method, the required parameters must be carefully written to the respective bit fields, to avoid unintended intermediate states.

Many applications change the frequency of the system clock ( $f_{SYS}$ ) during operation in order to optimize system performance and power consumption. Changing the operating frequency also changes the switching currents, which influences the power supply.

To ensure proper operation of the on-chip EVRs while they generate the core voltage, the operating frequency shall only be changed in certain steps. This prevents overshoots and undershoots of the supply voltage.

To avoid the indicated problems, recommended sequences are provided which ensure the intended operation of the clock system interacting with the power system. Please refer to the Programmer's Guide.



 Table 26 is valid under the following conditions:

 $V_{\text{DDP}} \ge 4.5 \text{ V}; V_{\text{DDPtyp}} = 5 \text{ V}; V_{\text{DDP}} \le 5.5 \text{ V}; C_{\text{L}} \ge 20 \text{ pF}; C_{\text{L}} \le 100 \text{ pF};$ 

	Table 26	Standard Pad	<b>Parameters</b>	for Upper	Voltage Range
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Parameter	Symbol		Values	5	Unit	Note /
		Min.	Тур.	Max.	1	Test Condition
Maximum output driver	I <sub>Omax</sub>	-	-	10	mA	Strong driver
current (absolute value) <sup>1)</sup>	CC	-	-	4.0	mA	Medium driver
		-	-	0.5	mA	Weak driver
Nominal output driver	I <sub>Onom</sub>	-	-	2.5	mA	Strong driver
current (absolute value)	CC	-	-	1.0	mA	Medium driver
		-	-	0.1	mA	Weak driver
Rise and Fall times (10% - 90%)	t <sub>RF</sub> CC	-	-	4.2 + 0.14 x <i>C</i> <sub>L</sub>	ns	Strong driver; Sharp edge
		-	-	11.6 + 0.22 x <i>C</i> <sub>L</sub>	ns	Strong driver; Medium edge
		-	-	20.6 + 0.22 x <i>C</i> <sub>L</sub>	ns	Strong driver; Slow edge
		_	-	23 + 0.6 x <i>C</i> L	ns	Medium driver
		-	-	212 + 1.9 x <i>C</i> L	ns	Weak driver

 The total output current that may be drawn at a given time must be limited to protect the supply rails from damage. For any group of 16 neighboring output pins, the total output current in each direction (ΣI<sub>OL</sub> and Σ-I<sub>OH</sub>) must remain below 50 mA.



## Table 31 EBC External Bus Timing for Lower Voltage Range

Symbol	Values			Unit	Note /
	Min.	Тур.	Max.	1	Test Condition
<i>t</i> <sub>10</sub> CC	-	11	20	ns	
<i>t</i> <sub>11</sub> CC	-	10	21	ns	
<i>t</i> <sub>12</sub> CC	-	11	22	ns	
<i>t</i> <sub>13</sub> CC	-	10	22	ns	
t <sub>14</sub> CC	-	10	13	ns	
<i>t</i> <sub>15</sub> CC	_	10	22	ns	
<i>t</i> <sub>16</sub> CC	_	10	22	ns	
<i>t</i> <sub>20</sub> CC	-2	8	10	ns	
<i>t</i> <sub>21</sub> CC	-2	8	10	ns	
<i>t</i> <sub>23</sub> CC	-3	8	10	ns	
t <sub>24</sub> CC	-3	8	11	ns	
<i>t</i> <sub>25</sub> CC	-3	8	10	ns	
<i>t</i> <sub>30</sub> SR	29	17	-	ns	
<i>t</i> <sub>31</sub> SR	0	-9	_	ns	
	$t_{10} CC$ $t_{11} CC$ $t_{12} CC$ $t_{13} CC$ $t_{14} CC$ $t_{15} CC$ $t_{20} CC$ $t_{21} CC$ $t_{23} CC$ $t_{23} CC$ $t_{25} CC$ $t_{30} SR$	Min. $t_{10}$ CC         - $t_{11}$ CC         - $t_{12}$ CC         - $t_{12}$ CC         - $t_{13}$ CC         - $t_{13}$ CC         - $t_{14}$ CC         - $t_{14}$ CC         - $t_{16}$ CC         - $t_{20}$ CC         -2 $t_{21}$ CC         -2 $t_{23}$ CC         -3 $t_{25}$ CC         -3 $t_{30}$ SR         29	Min.         Typ. $t_{10}$ CC         -         11 $t_{11}$ CC         -         10 $t_{12}$ CC         -         10 $t_{12}$ CC         -         11 $t_{12}$ CC         -         10 $t_{12}$ CC         -         10 $t_{13}$ CC         -         10 $t_{14}$ CC         -         10 $t_{15}$ CC         -         10 $t_{16}$ CC         -         10 $t_{20}$ CC         -2         8 $t_{21}$ CC         -2         8 $t_{23}$ CC         -3         8 $t_{25}$ CC         -3         8 $t_{30}$ SR         29         17	Min.Typ.Max. $t_{10}$ CC-1120 $t_{11}$ CC-1021 $t_{11}$ CC-1022 $t_{12}$ CC-1122 $t_{13}$ CC-1013 $t_{14}$ CC-1013 $t_{15}$ CC-1022 $t_{16}$ CC-1022 $t_{20}$ CC-2810 $t_{21}$ CC-3810 $t_{23}$ CC-3810 $t_{25}$ CC-3810 $t_{30}$ SR2917-	Min.Typ.Max. $t_{10}$ CC-1120ns $t_{11}$ CC-1021ns $t_{11}$ CC-1021ns $t_{12}$ CC-1122ns $t_{12}$ CC-1022ns $t_{13}$ CC-1013ns $t_{14}$ CC-1022ns $t_{14}$ CC-1022ns $t_{16}$ CC-1022ns $t_{16}$ CC-1022ns $t_{20}$ CC-2810ns $t_{21}$ CC-2810ns $t_{21}$ CC-3811ns $t_{23}$ CC-3810ns $t_{25}$ CC-3810ns $t_{30}$ SR2917-ns

 Read data are latched with the same internal clock edge that triggers the address change and the rising edge of RD. Address changes before the end of RD have no impact on (demultiplexed) read cycles. Read data can change after the rising edge of RD.



# XC2785X XC2000 Family / Base Line

### **Electrical Parameters**

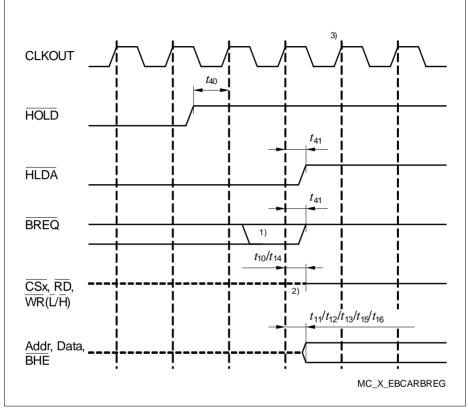


Figure 27 External Bus Arbitration, Regaining the Bus

### Notes

- 1. This is the last chance for BREQ to trigger the indicated regain sequence. Even if BREQ is activated earlier, the regain sequence is initiated by HOLD going high. Please note that HOLD may also be deactivated without the XC2785X requesting the bus.
- 2. The control outputs will be resistive high (pull-up) before being driven inactive (ALE will be low).
- 3. The next XC2785X-driven bus cycle may start here.



# 4.6.7 Debug Interface Timing

The debugger can communicate with the XC2785X either via the 2-pin DAP interface or via the standard JTAG interface.

### Debug via DAP

The following parameters are applicable for communication through the DAP debug interface.

Note: These parameters are not subject to production test but verified by design and/or characterization.

Note: Operating Conditions apply;  $C_L$ = 20 pF.

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.	_	Test Condition
DAP0 clock period	t <sub>11</sub> SR	25 <sup>1)</sup>	-	-	ns	
DAP0 high time	t <sub>12</sub> SR	8	-	-	ns	
DAP0 low time	t <sub>13</sub> SR	8	-	-	ns	
DAP0 clock rise time	t <sub>14</sub> SR	-	-	4	ns	
DAP0 clock fall time	t <sub>15</sub> SR	-	-	4	ns	
DAP1 setup to DAP0 rising edge	<i>t</i> <sub>16</sub> SR	6	-	-	ns	pad_type= stan dard
DAP1 hold after DAP0 rising edge	<i>t</i> <sub>17</sub> SR	6	-	-	ns	pad_type= stan dard
DAP1 valid per DAP0 clock period <sup>2)</sup>	<i>t</i> <sub>19</sub> CC	17	20	-	ns	pad_type= stan dard

 Table 38
 DAP Interface Timing for Upper Voltage Range

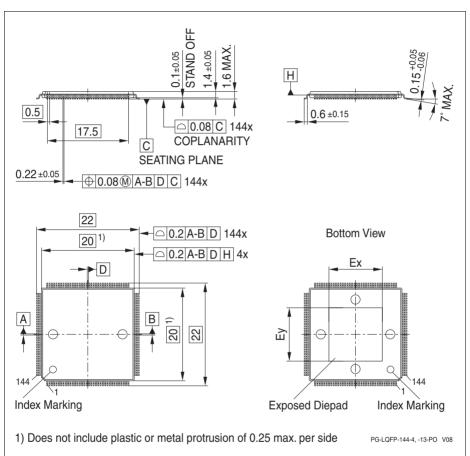
1) The debug interface cannot operate faster than the overall system, therefore  $t_{11} \ge t_{SYS}$ .

2) The Host has to find a suitable sampling point by analyzing the sync telegram response.



## Package and Reliability

# Package Outlines



## Figure 34 PG-LQFP-144-13 (Plastic Green Thin Quad Flat Package)

All dimensions in mm.

You can find complete information about Infineon packages, packing and marking in our Infineon Internet Page "Packages": http://www.infineon.com/packages



### Package and Reliability

# 5.2 Thermal Considerations

When operating the XC2785X in a system, the total heat generated in the chip must be dissipated to the ambient environment to prevent overheating and the resulting thermal damage.

The maximum heat that can be dissipated depends on the package and its integration into the target board. The "Thermal resistance  $R_{\Theta JA}$ " quantifies these parameters. The power dissipation must be limited so that the average junction temperature does not exceed 150 °C.

The difference between junction temperature and ambient temperature is determined by  $\Delta T = (P_{INT} + P_{IOSTAT} + P_{IODYN}) \times R_{\Theta,IA}$ 

The internal power consumption is defined as

 $P_{\text{INT}} = V_{\text{DDP}} \times I_{\text{DDP}}$  (switching current and leakage current).

The static external power consumption caused by the output drivers is defined as  $P_{\text{IOSTAT}} = \Sigma((V_{\text{DDP}} \cdot V_{\text{OH}}) \times I_{\text{OH}}) + \Sigma(V_{\text{OL}} \times I_{\text{OL}})$ 

The dynamic external power consumption caused by the output drivers ( $P_{IODYN}$ ) depends on the capacitive load connected to the respective pins and their switching frequencies.

If the total power dissipation for a given system configuration exceeds the defined limit, countermeasures must be taken to ensure proper system operation:

- Reduce  $V_{\text{DDP}}$ , if possible in the system
- Reduce the system frequency
- · Reduce the number of output pins
- Reduce the load on active output drivers

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